Integrated Relay, Inductive Load Driver

This device is used to switch inductive loads such as relays, solenoids incandescent lamps, and small DC motors without the need of a free—wheeling diode. The device integrates all necessary items such as the MOSFET switch, ESD protection, and Zener clamps. It accepts logic level inputs thus allowing it to be driven by a large variety of devices including logic gates, inverters, and microcontrollers.

Features

- Provides a Robust Driver Interface Between DC Relay Coil and Sensitive Logic Circuits
- Optimized to Switch Relays from 3.0 V to 5.0 V Rail
- Capable of Driving Relay Coils Rated up to 2.5 W at 5.0 V
- Internal Zener Eliminates the Need of Free-Wheeling Diode
- Internal Zener Clamp Routes Induced Current to Ground for Quieter Systems Operation
- Low V_{DS(on)} Reduces System Current Drain
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free Devices

Typical Applications

- Telecom: Line Cards, Modems, Answering Machines, FAX
- Computers and Office: Photocopiers, Printers, Desktop Computers
- Consumer: TVs and VCRs, Stereo Receivers, CD Players, Cassette Recorders
- Industrial:Small Appliances, Security Systems, Automated Test Equipment, Garage Door Openers
- Automotive: 5.0 V Driven Relays, Motor Controls, Power Latches, Lamp Drivers



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RELAY/INDUCTIVE LOAD DRIVER 0.5 AMPERE, 8.0 VOLT CLAMP

MARKING DIAGRAMS



SOT-23 (TO-236) CASE 318





SC-74 CASE 318F STYLE 7



JW4 = Device Code

M = Date Code*

D = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
NUD3105LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
NUD3105DMT1G	SOT-74 (Pb-Free)	3000 / Tape & Reel
SZNUD3105DMT1G	SOT-74 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

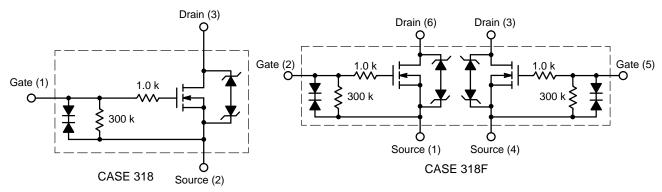


Figure 1. Internal Circuit Diagrams

MAXIMUM RATINGS ($T_J = 25^{\circ}C$ unless otherwise specified)

Symbol	Rating	Value	Unit	
V _{DSS}	Drain to Source Voltage – Continuous	6.0	V _{dc}	
V _{GS}	Gate to Source Voltage – Continuous		6.0	V _{dc}
I _D	Drain Current – Continuous		500	mA
Ez	Single Pulse Drain-to-Source Avalanche Energy (T	Jinitial = 25°C) (Note 2)	50	mJ
E _{zpk}	Repetitive Pulse Zener Energy Limit (DC ≤ 0.01%)	(f = 100 Hz, DC = 0.5)	4.5	mJ
TJ	Junction Temperature	150	°C	
T _A	Operating Ambient Temperature	-40 to 85	°C	
T _{stg}	Storage Temperature Range	-65 to +150	°C	
P _D	Total Power Dissipation (Note 1) Derating Above 25°C	SOT-23	225 1.8	mW mW/°C
	Total Power Dissipation (Note 1) Derating Above 25°C	SC-74	380 1.5	mW mW/°C
$R_{ heta JA}$	Thermal Resistance, Junction-to-Ambient	SOT-23 SC-74	556 329	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Symbol	Characteristic	Min	Тур	Max	Unit			
OFF CHARAC	OFF CHARACTERISTICS							
V _{BRDSS}	Drain to Source Sustaining Voltage (Internally Clamped), (I _D = 10 mA)	6.0	8.0	9.0	V			
B _{VGSO}	I _g = 1.0 mA	-	-	8.0	V			
I _{DSS}	Drain to Source Leakage Current $(V_{DS} = 5.5 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 25^{\circ}\text{C})$ $(V_{DS} = 5.5 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 85^{\circ}\text{C})$	- -	- -	15 15	μΑ			
I _{GSS}	Gate Body Leakage Current (318) (V _{GS} = 3.0 V, V _{DS} = 0 V) (V _{GS} = 5.0 V, V _{DS} = 0 V)	5.0 -	-	19 50	μΑ			
	Gate Body Leakage Current (318F) (V _{GS} = 3.0 V, V _{DS} = 0 V) (V _{GS} = 5.0 V, V _{DS} = 0 V)	5.0 –	1 1	35 65	μΑ			

^{1.} This device contains ESD protection and exceeds the following tests: Human Body Model 2000 V per MIL_STD-883, Method 3015. Machine Model Method 200 V.

^{2.} Refer to the section covering Avalanche and Energy.

ELECTRICAL CHARACTERISTICS (T_{.1} = 25°C unless otherwise noted)

Symbol	Characteristic	Min	Тур	Max	Unit
N CHARAC	TERISTICS				
V _{GS(th)}	Gate Threshold Voltage $(V_{GS} = V_{DS}, I_D = 1.0 \text{ mA})$ $(V_{GS} = V_{DS}, I_D = 1.0 \text{ mA}, T_J = 85^{\circ}\text{C})$	0.8 0.8	1.2 -	1.4 1.4	V
R _{DS(on)}	Drain to Source On–Resistance $ \begin{array}{l} (I_D = 250 \text{ mA, V}_{GS} = 3.0 \text{ V}) \\ (I_D = 500 \text{ mA, V}_{GS} = 3.0 \text{ V}) \\ (I_D = 500 \text{ mA, V}_{GS} = 5.0 \text{ V}) \\ (I_D = 500 \text{ mA, V}_{GS} = 5.0 \text{ V}, T_{J}=85^{\circ}\text{C}) \\ (I_D = 500 \text{ mA, V}_{GS} = 5.0 \text{ V}, T_{J}=85^{\circ}\text{C}) \end{array} $	- - - -	- - - -	1.2 1.3 0.9 1.3 0.9	Ω
I _{DS(on)}	Output Continuous Current ($V_{DS} = 0.25 \text{ V}, V_{GS} = 3.0 \text{ V}$) ($V_{DS} = 0.25 \text{ V}, V_{GS} = 3.0 \text{ V}, T_{J} = 85^{\circ}\text{C}$)	300 200	400 -	-	mA
9FS	Forward Transconductance (V _{OUT} = 5.0 V, I _{OUT} = 0.25 A)	350	570	-	mmhos
YNAMIC CH	ARACTERISTICS				
C _{iss}	Input Capacitance (V _{DS} = 5.0 V,V _{GS} = 0 V, f = 10 kHz)	-	25	-	pF
C _{oss}	Output Capacitance $(V_{DS} = 5.0 \text{ V}, V_{GS} = 0 \text{ V}, f = 10 \text{ kHz})$	-	37	-	pF
C _{rss}	Transfer Capacitance $(V_{DS} = 5.0 \text{ V}, V_{GS} = 0 \text{ V}, f = 10 \text{ kHz})$	-	8.0	-	pF

SWITCHING CHARACTERISTICS

Symbol	Characteristic	Min	Тур	Max	Units
^t PHL ^t PLH	Propagation Delay Times: High to Low Propagation Delay; Figure 1 (5.0 V) Low to High Propagation Delay; Figure 1 (5.0 V)	- -	25 80	- -	nS
t _{PHL} t _{PLH}	High to Low Propagation Delay; Figure 1 (3.0 V) Low to High Propagation Delay; Figure 1 (3.0 V)	-	44 44	_ _	
t _f tr	Transition Times: Fall Time; Figure 1 (5.0 V) Rise Time; Figure 1 (5.0 V)	- -	23 32	- -	nS
t _f t _r	Fall Time; Figure 1 (3.0 V) Rise Time; Figure 1 (3.0 V)		53 30	- -	

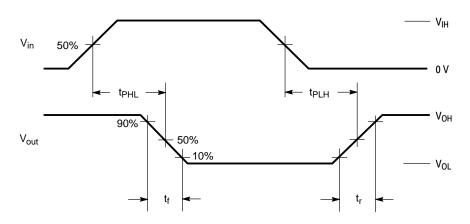


Figure 1. Switching Waveforms

TYPICAL CHARACTERISTICS

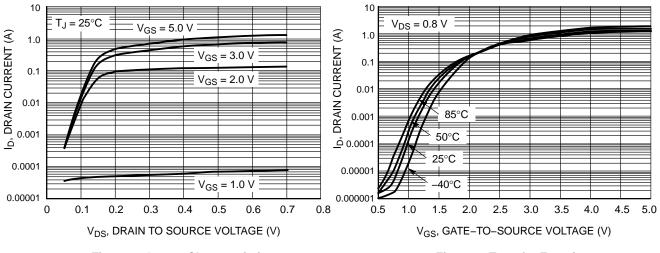


Figure 2. Output Characteristics

Figure 3. Transfer Function

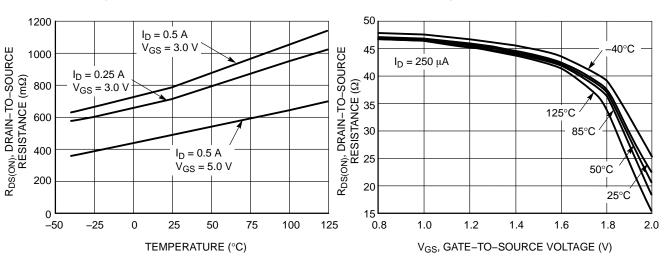


Figure 4. On Resistance Variation vs. Temperature

Figure 5. R_{DS(ON)} Variation with Gate-To-Source Voltage

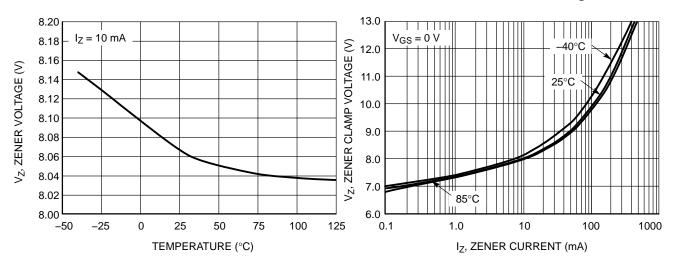


Figure 6. Zener Voltage vs. Temperature

Figure 7. Zener Clamp Voltage vs. Zener Current

TYPICAL CHARACTERISTICS

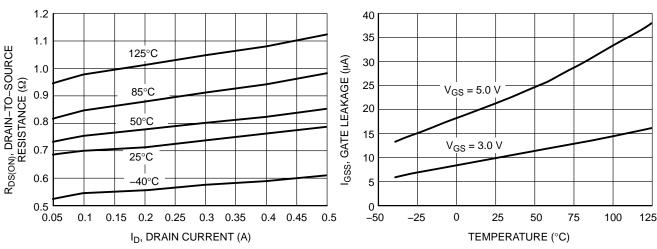


Figure 8. On–Resistance vs. Drain Current and Temperature

Figure 9. Gate Leakage vs. Temperature

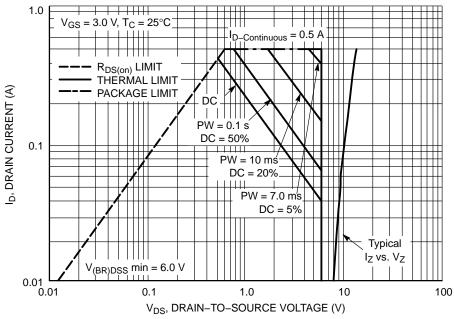


Figure 10. Safe Operating Area

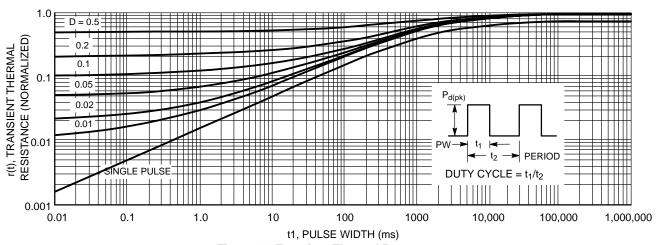


Figure 11. Transient Thermal Response

Designing with this Data Sheet

- 1. Determine the maximum inductive load current (at max V_{CC} , min coil resistance & usually minimum temperature) that the NUD3105 will have to drive and make sure it is less than the max rated current.
- 2. For pulsed operation, use the Transient Thermal Response of Figure 11 and the instructions with it to determine the maximum limit on transistor power dissipation for the desired duty cycle and temperature range.
- 3. Use Figures 10 and 11 with the SOA notes to insure that instantaneous operation does not push the device beyond the limits of the SOA plot.

- Verify that the circuit driving the gate will meet the V_{GS(th)} from the Electrical Characteristics table
- 5. Using the max output current calculated in step 1, check Figure 7 to insure that the range of Zener clamp voltage over temperature will satisfy all system & EMI requirements.
- Use I_{GSS} and I_{DSS} from the Electrical Characteristics table to ensure that "OFF" state leakage over temperature and voltage extremes does not violate any system requirements.
- 7. Review circuit operation and insure none of the device max ratings are being exceeded.

APPLICATIONS DIAGRAMS

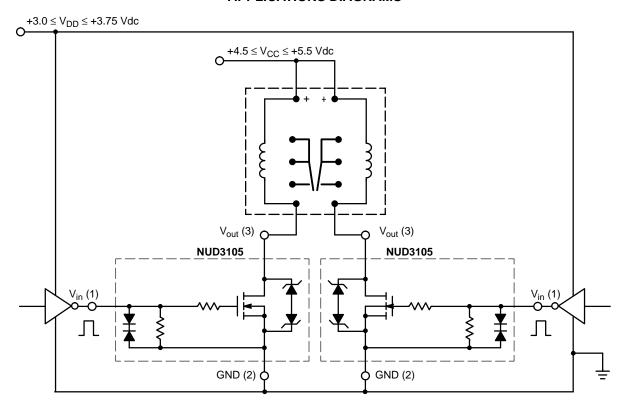


Figure 12. A 200 mW, 5.0 V Dual Coil Latching Relay Application with 3.0 V Level Translating Interface

Max Continuous Current Calculation

for TX2–5V Relay, R1 = 178 Ω Nominal @ R_A = 25°C Assuming $\pm 10\%$ Make Tolerance, R1 = 178 Ω * 0.9 = 160 Ω Min @ T_A = 25°C T_C for Annealed Copper Wire is 0.4%/°C R1 = 160 Ω * [1+(0.004) * (-40°-25°)] = 118 Ω Min @ -40°C I_O Max = (5.5 V Max – 0.25V) /118 Ω = 45 mA

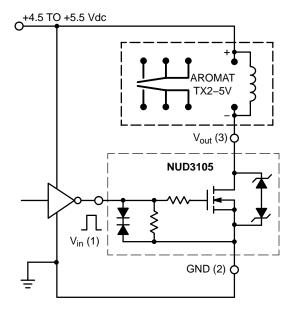


Figure 13. A 140 mW, 5.0 V Relay with TTL Interface

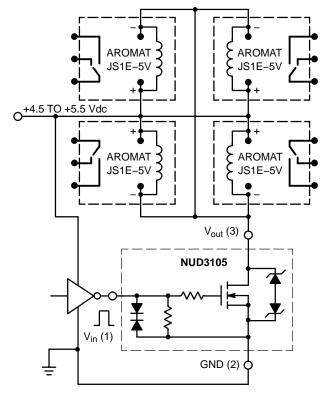
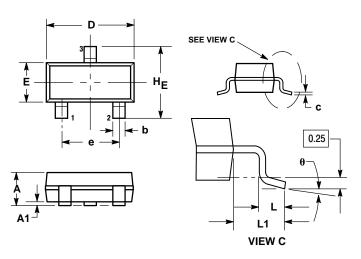


Figure 14. A Quad 5.0 V, 360 mW Coil Relay Bank

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AP**

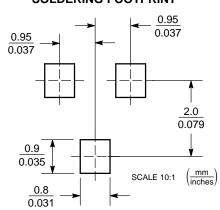


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
 4. DIMENSIONS O AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

 MILLIMETERS INCHES

	М	ILLIMETE	RS	INCHES			
DIM	MIN	NOM	MAX	MIN NOM MA			
Α	0.89	1.00	1.11	0.035	0.040	0.044	
A1	0.01	0.06	0.10	0.001	0.002	0.004	
b	0.37	0.44	0.50	0.015	0.018	0.020	
С	0.09	0.13	0.18	0.003	0.005	0.007	
D	2.80	2.90	3.04	0.110	0.114	0.120	
E	1.20	1.30	1.40	0.047	0.051	0.055	
е	1.78	1.90	2.04	0.070	0.075	0.081	
L	0.10	0.20	0.30	0.004	0.008	0.012	
L1	0.35	0.54	0.69	0.014	0.021	0.029	
HE	2.10	2.40	2.64	0.083	0.094	0.104	
θ	0°		10°	0°		10°	

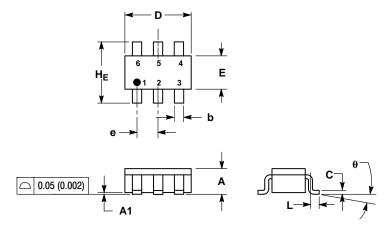
SOLDERING FOOTPRINT*



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PACKAGE DIMENSIONS

SC-74 CASE 318F-05 ISSUE N



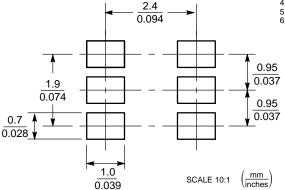
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- IES.
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- 4. 318F-01, -02, -03, -04 OBSOLETE. NEW STANDARD 318F-05.

	MILLIMETERS INCHES					
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.90	1.00	1.10	0.035	0.039	0.043
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.25	0.37	0.50	0.010	0.015	0.020
С	0.10	0.18	0.26	0.004	0.007	0.010
D	2.90	3.00	3.10	0.114	0.118	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
е	0.85	0.95	1.05	0.034	0.037	0.041
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.75	3.00	0.099	0.108	0.118
θ	0°	-	10°	0°	-	10°

STYLE 7: PIN 1. SOURCE 1

- 2. GATE 1 3. DRAIN 2
- SOURCE 2 GATE 2
- DRAIN 1



SOLDERING FOOTPRINT*

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